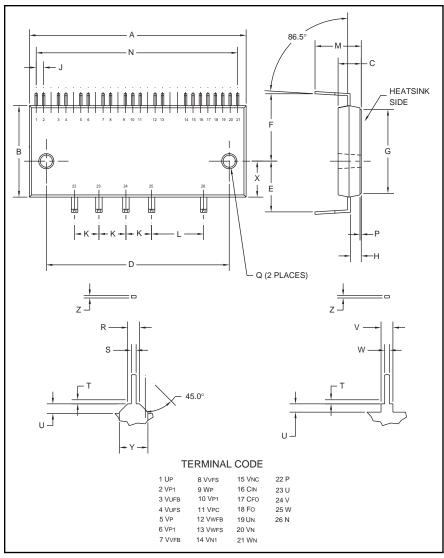


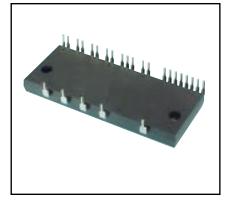
# Intellimod<sup>™</sup> Module Dual-In-Line Intelligent Power Module 20 Amperes/600 Volts



#### **Outline Drawing and Circuit Diagram**

Dimensions	Inches	Millimeters
Α	3.07±0.02	79.0±0.5
В	1.22±0.02	31.0±0.5
С	0.32±0.02	8.0±0.5
D	2.64±0.01	67.0±0.3
Е	0.53±0.01 Dia.	13.4±0.2 Dia.
F	0.84±0.02	21.4±0.5
G	1.10±0.02	28.0±0.5
Н	0.15±0.01	3.8±0.2
J	0.11±0.01	2.8±0.3
K	0.39±0.01	10.0±0.3
L	0.79±0.01	20.0±0.3
М	0.50±0.04	12.8±1.0

Dimensions	Inches	Millimeters
N	2.98	75.6
Р	0.02±0.01	0.5±0.2
Q	0.18±0.01 Dia.	4.5±0.2 Dia.
R	0.08±0.02	1.9±0.05
S	0.04±0.01	1.0±0.2
Т	0.02 Max.	0.5 Max.
U	0.02±0.02	0.6±0.5
V	0.07 Max.	1.75 Max.
W	0.03±0.01	0.8±0.2
X	0.45±0.02	11.5±0.5
Y	0.13 Max.	3.25 Max.
Z	0.03	0.7



#### **Description:**

DIP and mini-DIP IPMs are intelligent power modules that integrate power devices, drivers, and protection circuitry in an ultra compact dual-in-line transfer-mold package for use in driving small three phase motors. Use of 4th generation IGBTs, DIP packaging, and application specific HVICs allow the designer to reduce inverter size and overall design time.

#### Features:

	Compact Packages
П	Single Power Supply

ш	omgio i omoi	Oabl
	Integrated HV	/ICs

D:	Connection	4-	$\sim$ DI	п
 THEACT	L.MNDACTION	11		

Optimized	for	5kHz	On	aration
Optimized	101	OKITZ	Oρ	zialion

#### **Applications:**

Ш	vvasning	giviacnines

□ Refrigerators

☐ Air Conditioners

☐ Small Servo Motors

☐ Small Motor Control

### **Ordering Information:**

PS21445-E is a 600V, 20 Ampere DIP Intelligent Power Module.



PS21445-E Intellimod™ Module Dual-In-Line Intelligent Power Module 20 Amperes/600 Volts

## Absolute Maximum Ratings, $T_j = 25^{\circ}\text{C}$ unless otherwise specified

Characteristics	Symbol	PS21445-E	Units
Power Device Junction Temperature*	T <sub>j</sub>	-20 to 150	°C
Storage Temperature	T <sub>stg</sub>	-40 to 125	°C
Case Operating Temperature (See T <sub>C</sub> Measure Point Illustration)	T <sub>C</sub>	-20 to 100	°C
Mounting Torque, M4 Mounting Screws	_	13	in-lb
Module Weight (Typical)	_	54	Grams
Heatsink Flatness	_	-50 to 100	μm
Self-protection Supply Voltage Limit (Short Circuit Protection Capability)**	V <sub>CC(prot.)</sub>	400	Volts
Isolation Voltage, AC 1 minute, 60Hz Sinusoidal, Connection Pins to Heatsink Plate	V <sub>ISO</sub>	2500	Volts

<sup>\*</sup>The maximum junction temperature rating of the power chips integrated within the DIP-IPM is  $150^{\circ}\text{C}$  (@T<sub>C</sub>  $\leq 100^{\circ}\text{C}$ ). However, to ensure safe operation of the DIP-IPM, the average junction temperature should be limited to T<sub>|[avg|</sub>  $\leq 125^{\circ}\text{C}$  (@T<sub>C</sub>  $\leq 100^{\circ}\text{C}$ ).

\*\*V<sub>D</sub> = V<sub>DB</sub> =  $13.5 \sim 16.5\text{V}$ , Inverter Part, T<sub>j</sub> =  $125^{\circ}\text{C}$ , Non-repetitive, Less than 2µs

#### **IGBT Inverter Sector**

Collector-Emitter Voltage	V <sub>CES</sub>	600	Volts
Collector Current, $\pm$ (T <sub>C</sub> = 25°C)	IC	20	Amperes
Peak Collector Current, $\pm$ (T <sub>C</sub> = 25°C, Instantaneous Value (Pulse))	I <sub>CP</sub>	40	Amperes
Supply Voltage (Applied between P - N)	V <sub>CC</sub>	450	Volts
Supply Voltage, Surge (Applied between P - N)	V <sub>CC(surge)</sub>	500	Volts
Collector Dissipation (T <sub>C</sub> = 25°C, per 1 Chip)	P <sub>C</sub>	56	Watts

#### **Control Sector**

Supply Voltage (Applied between V <sub>P1</sub> -V <sub>PC</sub> , V <sub>N1</sub> -V <sub>NC</sub> )	V <sub>D</sub>	20	Volts
Supply Voltage (Applied between V <sub>UFB</sub> -V <sub>UFS</sub> , V <sub>VFB</sub> -V <sub>VFS</sub> , V <sub>WFB</sub> -V <sub>WFS</sub> )	$V_{DB}$	20	Volts
Input Voltage (Applied between Up, Vp, Wp-VpC, U <sub>N</sub> , V <sub>N</sub> , W <sub>N</sub> -V <sub>NC</sub> )	V <sub>CIN</sub>	-0.5 ~ 5.5	Volts
Fault Output Supply Voltage (Applied between F <sub>O</sub> -V <sub>NC</sub> )	$V_{FO}$	-0.5 ~ V <sub>D</sub> +0.5	Volts
Fault Output Current (Sink Current at F <sub>O</sub> Terminal)	I <sub>FO</sub>	15	mA
Current Sensing Input Voltage (Applied between C <sub>IN</sub> -V <sub>NC</sub> )	V <sub>SC</sub>	-0.5 ~ V <sub>D</sub> +0.5	Volts

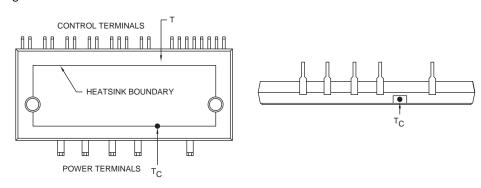


PS21445-E Intellimod™ Module Dual-In-Line Intelligent Power Module 20 Amperes/600 Volts

# Electrical and Mechanical Characteristics, $T_i = 25^{\circ}\text{C}$ unless otherwise specified

Characteristics Symbol Test Conditions				Тур.	Max.	Units
IGBT Inverter Sector						
Collector Cutoff Current	I <sub>CES</sub>	$V_{CE} = V_{CES}, T_j = 25^{\circ}C$	_	_	1.0	mA
		$V_{CE} = V_{CES}$ , $T_j = 125$ °C	_	_	10	mA
Diode Forward Voltage	$V_{EC}$	$T_j = 25^{\circ}C$ , $-I_C = 20A$ , $V_{CIN} = 5V$	_	2.2	3.0	Volts
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_C = 20A$ , $T_j = 25$ °C, $V_D = V_{DB} = 15V$ , $V_{CIN} = 0V$	_	1.55	2.15	Volts
		$I_C = 20A$ , $T_j = 125$ °C, $V_D = V_{DB} = 15V$ , $V_{CIN} = 0V$	_	1.65	2.25	Volts
Inductive Load Switching Times	t <sub>on</sub>	$V_{CC} = 300V, V_D = 15V,$	0.1	0.8	1.3	μS
	t <sub>rr</sub>	I <sub>C</sub> = 20A,	_	0.1	_	μS
	t <sub>C(on)</sub>	T <sub>j</sub> = 125°C,	_	0.5	0.9	μS
	t <sub>off</sub>	Inductive Load (Upper-Lower Arm),	_	1.6	2.7	μS
	t <sub>C(off)</sub>	V <sub>CIN</sub> = 5V(off), 0V(on)	_	1.0	1.9	μS

#### T<sub>C</sub> Measure Point





PS21445-E Intellimod™ Module Dual-In-Line Intelligent Power Module 20 Amperes/600 Volts

# Electrical and Mechanical Characteristics, $T_j$ = 25°C unless otherwise specified

Characteristics	Symb	ol Test Conditions	Min.	Typ.	Max.	Units		
Control Sector								
Supply Voltage	V <sub>D</sub>	Applied between V <sub>P1</sub> -V <sub>PC</sub> , V <sub>N1</sub> -V <sub>NC</sub>	13.5	15.0	16.5	Volts		
	V <sub>DB</sub>	Applied between V <sub>UFB</sub> -V <sub>UFS</sub> ,	13.5	15.0	16.5	Volts		
		V <sub>VFB</sub> -V <sub>VFS</sub> , V <sub>WFB</sub> -V <sub>WFS</sub>						
Circuit Current	I <sub>D</sub>	$V_D = V_{DB} = 15V$ , Input = OFF	_	_	8.50	mA		
		Total of VP1-VPC, VN1-VNC						
		$V_D = V_{DB} = 15V$ , Input = ON	_	_	9.70	mA		
		Total of V <sub>P1</sub> -V <sub>PC</sub> , V <sub>N1</sub> -V <sub>NC</sub>						
	_	$V_D = V_{DB} = 15V$ , Input = OFF	_	_	1.00	mA		
		$V_{UFB}\text{-}V_{UFS}, V_{VFB}\text{-}V_{VFS}, V_{WFB}\text{-}V_{WFS}$						
	_	$V_D = V_{DB} = 15V$ , Input = ON	_	_	1.00	mA		
		$V_{UFB}$ - $V_{UFS}$ , $V_{VFB}$ - $V_{VFS}$ , $V_{WFB}$ - $V_{WFS}$						
Fault Output Voltage	V <sub>FOH</sub>	$V_{SC}$ = 0V, $F_{O}$ Circuit: 10k $\Omega$ to 5V Pull-up	4.9	_	_	Volts		
	V <sub>FOL</sub>	$V_{SC}$ = 1V, $F_O$ Circuit: 10k $\Omega$ to 5V Pull-up	_	0.8	1.2	Volts		
	V <sub>FO(sat)</sub>	$V_{SC} = 1V$ , $I_{FO} = 15mA$	0.8	1.2	1.8	Volts		
PWM Input Frequency	$f_{PWM}$	$T_C \le 100^{\circ}C$ , $T_j \le 125^{\circ}C$	_	5	_	kHz		
Allowable Dead Time	t <sub>DEAD</sub>	Relates to Corresponding Input Signal for	2.5	_	_	μS		
	В	llocking Arm Shoot-through (-20°C $\leq$ T <sub>C</sub> $\leq$ 100°C	;)					
Short Circuit Trip Level*	V <sub>SC(ref)</sub>	$T_j = 25^{\circ}C, V_D = 15V^*$	0.45	0.5	0.55	Volts		
Supply Circuit Under-voltage	UV <sub>DBt</sub>	Trip Level, T <sub>j</sub> ≤ 125°C	10.0	_	12.0	Volts		
	UV <sub>DBr</sub>	Reset Level, T <sub>j</sub> ≤ 125°C	10.5	_	12.5	Volts		
	UV <sub>Dt</sub>	Trip Level, T <sub>j</sub> ≤ 125°C	10.3	_	12.5	Volts		
	UV <sub>Dr</sub>	Reset Level, T <sub>j</sub> ≤ 125°C	10.8	_	13.0	Volts		
Fault Output Pulse Width**	t <sub>FO</sub>	C <sub>FO</sub> = 22nF	1.0	1.8		mS		
ON Threshold Voltage (H-side)	V <sub>th(on)</sub>	Applied between U <sub>P</sub> , V <sub>P</sub> , W <sub>P</sub> -V <sub>PC</sub>	0.8	1.4	2.0	Volts		
OFF Threshold Voltage (H-side)	V <sub>th(off)</sub>		2.5	3.0	4.0	Volts		
ON Threshold Voltage (L-side)	V <sub>th(on)</sub>	Applied between U <sub>N</sub> , V <sub>N</sub> , W <sub>N</sub> -V <sub>NC</sub>	0.8	1.4	2.0	Volts		
OFF Threshold Voltage (L-side)	V <sub>th(off)</sub>		2.5	3.0	4.0	Volts		

<sup>\*</sup> Short Circuit protection is functioning only at the low-arms. Please select the value of the external shunt resistor such that the SC trip level is less than 25.5A.

<sup>\*\*</sup>Fault signal is asserted when the low-arm short circuit or control supply under-voltage protective functions operate. The fault output pulse-width t<sub>FO</sub> depends on the capacitance value of C<sub>FO</sub> according to the following approximate equation: C<sub>FO</sub> = (12.2 x 10<sup>-6</sup>) x t<sub>FO</sub> {F}.



PS21445-E Intellimod™ Module Dual-In-Line Intelligent Power Module 20 Amperes/600 Volts

#### **Thermal Characteristics**

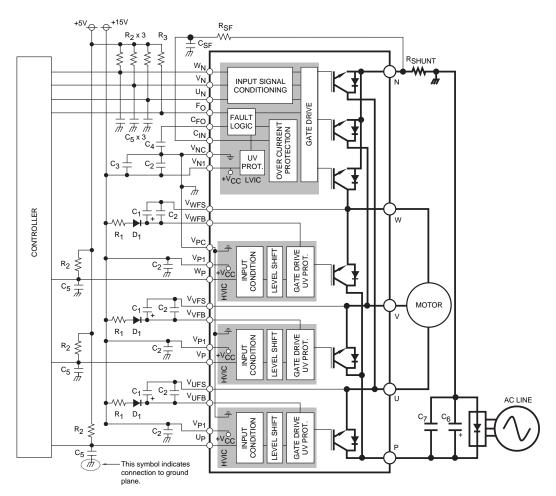
Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case	R <sub>th(j-c)Q</sub>	Each IGBT	_	_	2.2	°C/Watt
	R <sub>th(j-c)D</sub>	Each FWDi	_	_	4.5	°C/Watt
Contact Thermal Resistance	R <sub>th(c-f)</sub>	Case to Fin Per Module.	_	_	0.067	°C/Watt
		Thermal Grease Applied				

#### **Recommended Conditions for Use**

Characteristic	Symbol	Condition	Min.	Тур.	Value	Units
Supply Voltage	V <sub>CC</sub>	Applied between P-N Terminals	0	300	400	Volts
Control Supply Voltage	V <sub>D</sub>	Applied between V <sub>P1</sub> -V <sub>PC</sub> , V <sub>N1</sub> -V <sub>NC</sub>	13.5	15.0	16.5	Volts
	V <sub>DB</sub>	Applied between V <sub>UFB</sub> -V <sub>UFS</sub> ,	13.5	15.0	16.5	Volts
		$V_{VFB}$ - $V_{VFS}$ , $V_{WFB}$ - $V_{WFS}$				
Control Supply dv/dt	dV <sub>D</sub> /dt, dV <sub>DB</sub> /dt		-1	_	1	V/μs
Input ON Voltage	V <sub>CIN(on)</sub>	Applied between U <sub>P</sub> , V <sub>P</sub> , W <sub>P</sub> -V <sub>PC</sub>			0 ~ 0.65	Volts
Input OFF Voltage	V <sub>CIN(off)</sub>	Applied between U <sub>N</sub> , V <sub>N</sub> , W <sub>N</sub> -V <sub>NC</sub>			4.0 ~ 5.5	Volts
PWM Input Frequency	f <sub>PWM</sub>	$T_{C} \le 100^{\circ}\text{C}, T_{j} \le 125^{\circ}\text{C}$	_	5	_	kHz
Arm Shoot-through Blocking Time	t <sub>DEAD</sub>	For Each Input Signal	2.5	_	_	μS



#### PS21445-E Intellimod™ Module Dual-In-Line Intelligent Power Module 20 Amperes/600 Volts



Component	Salaction:

Dsgn.	Typ. Value	Description
D <sub>1</sub>	1A, 600V	Boot strap supply diode – Ultra fast recovery
C <sub>1</sub>	10-100uF, 50V	Boot strap supply reservoir – Electrolytic, long life, low Impedance, 105°C (Note 5)
$C_2$	0.22-2.0uF, 50V	Local decoupling/High frequency noise filters - Multilayer ceramic (Note 8)
$c_3$	1-100uF, 50V	Control power supply filter - Electrolytic, long life, low Impedance, 105°C
C <sub>4</sub>	22nF, 50V	Fault lock-out timing capacitor – Multilayer ceramic (Note 4)
C <sub>5</sub>	100-1000pF, 50V	Input signal noise filter – Multilayer ceramic (Note 1)
C <sub>6</sub>	200-2000uF, 450V	Main DC bus filter capacitor - Electrolytic, long life, high ripple current, 105°C
C <sub>7</sub>	0.1-0.22uF, 450V	Surge voltage suppression capacitor – Polyester/Polypropylene film (Note 9)
C <sub>SF</sub>	1000pF, 50V	Short circuit detection filter capacitor - Multilayer Ceramic (Note 6, Note 7)
RSF	1.8k ohm	Short circuit detection filter resistor (Note 6, Note 7)
RSHUNT	5-100 mohm	Current sensing resistor - Non-inductive, temperature stable, tight tolerance (Note 10)
R <sub>1</sub>	1-100 ohm	Boot strap supply inrush limiting resistor (Note 5)
R <sub>2</sub>	4.7k ohm	Control input pull-up resistor (Note 1, Note 2)
R <sub>3</sub>	5.1k ohm	Fault output signal pull-up resistor (Note 3)

- 1) To prevent input signal oscillations minimize wiring length to controller (~2cm). Additional RC filtering (C5 etc.) may be required. If filtering is added be careful to maintain proper dead time. See application notes for details.

  2) Internal HVIC provides high voltage level shifting allowing direct connection of all six driving signals to the controller.
- 2) internal TVIO provides insign exercises a similar almost an insign and the control of the state of the st

- 5) Boot strap supply component values must be adjusted depending on the PWM frequency and technique.
  6) Wiring length associated with R<sub>SHUNT</sub>, R<sub>SF</sub>, C<sub>SF</sub> must be minimized to avoid improper operation of the OC function.
  7) R<sub>SF</sub>, C<sub>SF</sub> set over current protection trip time. Recommend time constant is 1.5us-2.0us. See application notes.
- 8) Local decoupling/high frequency filter capacitors must be connected as close as possible to the modules pins.
- 9) The length of the DC link wiring between C6, C7, the DIP's P terminal and the shunt must be minimized to prevent
- excessive transient voltages. In particular C7 should be mounted as close to the DIP as possible.
- 10) Use high quality, tight tolorance current sensing resistor. Connect resistor as close as possible to the DIP's N terminal. Be careful to check for proper power rating. See application notes for calculation of resistance value.